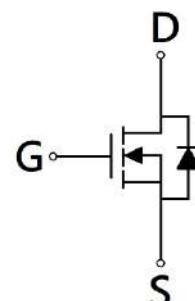
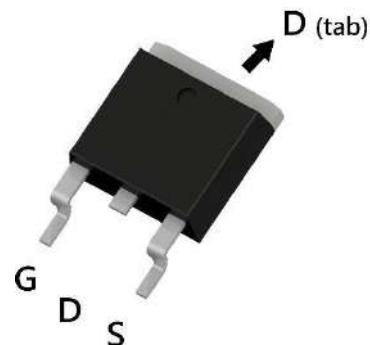


N-Channel Enhancement Mode Power MOSFET

Features:

- Low On Resistance
- Low Gate Charge
- Fast Switching Characteristic

TO-263



G : Gate S : Source D : Drain

BV _{DSS}	200V
I _D @V _{GS} =10V, T _C =25°C	48A
I _D @V _{GS} =10V, T _A =25°C	8A
R _{D(S)} (ON) typ. @V _{GS} =10V, I _D =10A	28mΩ

Ordering Information

Device	Package	Shipping
KUE30N20	TO-263 (Pb-free lead plating and RoHS compliant package)	800 pcs / Tape & Reel

Absolute Maximum Ratings ($T_A=25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Drain-Source Voltage	V_{DS}	200	V
Gate-Source Voltage	V_{GS}	± 20	
Continuous Drain Current @ $V_{GS}=10\text{V}$, $T_c=25^\circ\text{C}$	I_D	48	A
Continuous Drain Current @ $V_{GS}=10\text{V}$, $T_c=100^\circ\text{C}$		30	
Continuous Drain Current @ $V_{GS}=10\text{V}$, $T_A=25^\circ\text{C}$		8	
Continuous Drain Current @ $V_{GS}=10\text{V}$, $T_A=70^\circ\text{C}$		6	
Pulsed Drain Current	I_{DM}	192	mJ
Continuous Body Diode Forward Current @ $T_c=25^\circ\text{C}$	I_S	48	
Avalanche Current @ $L=0.1\text{mH}$	I_{AS}	22	
Avalanche Energy @ $L=0.5\text{mH}$	E_{AS}	25	
Total Power Dissipation	P_D	208	W
		83	
		5.7	
		3.6	
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-55~+150	$^\circ\text{C}$

Thermal Data

Parameter	Symbol	Steady State	Unit
Thermal Resistance, Junction-to-case	$R_{\theta JC}$	0.6	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-ambient	$R_{\theta JA}$	22	

Note:

- *a. The power dissipation P_D is based on $T_{J(MAX)}=150^\circ\text{C}$, using junction-to-case thermal resistance, and is more useful in setting the upper dissipation limit for cases where additional heatsinking is used.
- *b. The value of $R_{\theta JA}$ is measured with the device mounted on 1 in² FR -4 board with 2 oz. copper, in a still air environment with $T_A=25^\circ\text{C}$. The power dissipation P_D is based on $R_{\theta JA}$ and the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- *c. Repetitive rating, pulse width limited by junction temperature $T_{J(MAX)}=150^\circ\text{C}$. Ratings are based on low frequency and low duty cycles to keep initial $T_J=25^\circ\text{C}$.

Electrical Characteristics ($T_A=25^\circ\text{C}$, unless otherwise specified)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions	
Static						
BV_{DSS}	200	-	-	V	$\text{V}_{\text{GS}}=0\text{V}, \text{I}_D=250\mu\text{A}$	
$\text{V}_{\text{GS(th)}}$	2	-	4		$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, \text{I}_D=250\mu\text{A}$	
G_{FS}	-	24	-	S	$\text{V}_{\text{DS}}=10\text{V}, \text{I}_D=10\text{A}$	
I_{GSS}	-	-	± 100	nA	$\text{V}_{\text{GS}}=\pm 20\text{V}, \text{V}_{\text{DS}}=0\text{V}$	
I_{DSS}	-	-	1	μA	$\text{V}_{\text{DS}}=160\text{V}, \text{V}_{\text{GS}}=0\text{V}$	
$\text{R}_{\text{DS(ON)}}$	-	28	37	$\text{m}\Omega$	$\text{V}_{\text{GS}}=10\text{V}, \text{I}_D=10\text{A}$	
Dynamic						
C_{iss}	-	3450	-	pF	$\text{V}_{\text{DS}}=100\text{V}, \text{V}_{\text{GS}}=0\text{V}, f=1\text{MHz}$	
C_{oss}	-	180	-			
Crss	-	45	-	Ω	$f=1\text{MHz}$	
R_{g}	-	1.3	-			
Q_{g} *1, 2	-	76	-	nC	$\text{V}_{\text{DS}}=100\text{V}, \text{I}_D=10\text{A}, \text{V}_{\text{GS}}=10\text{V}$	
Q_{gs} *1, 2	-	14	-			
Q_{gd} *1, 2	-	26	-	ns	$\text{V}_{\text{DS}}=100\text{V}, \text{I}_D=10\text{A}, \text{V}_{\text{GS}}=10\text{V}, \text{R}_{\text{GS}}=5.6\Omega$	
$\text{t}_{\text{d(ON)}}$ *1, 2	-	32	-			
tr *1, 2	-	34	-	ns	$\text{V}_{\text{DS}}=100\text{V}, \text{I}_D=10\text{A}, \text{V}_{\text{GS}}=10\text{V}, \text{R}_{\text{GS}}=5.6\Omega$	
$\text{t}_{\text{d(OFF)}}$ *1, 2	-	88	-			
t_{f} *1, 2	-	32	-			
Source-Drain Diode						
V_{SD} *1	-	0.76	1.2	V	$\text{I}_{\text{S}}=10\text{A}, \text{V}_{\text{GS}}=0\text{V}$	
trr	-	86	-	ns	$\text{I}_{\text{F}}=10\text{A}, \frac{d\text{I}_{\text{F}}}{dt}=100\text{A}/\mu\text{s}$	
Qrr	-	375	-	nC		

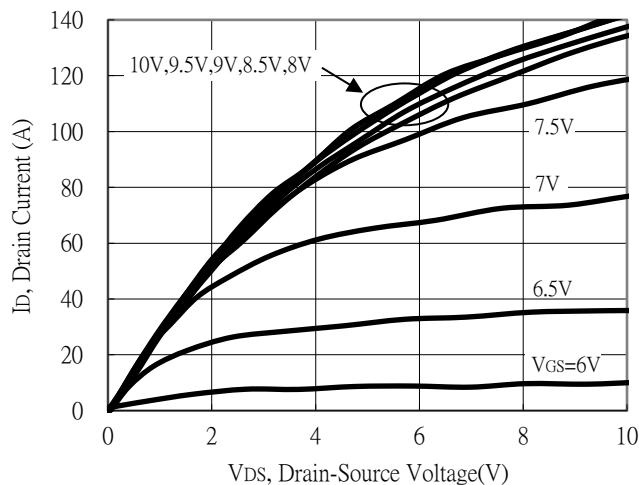
Note:

*1. Pulse Test : Pulse Width $\leq 300\mu\text{s}$, Duty Cycle $\leq 2\%$

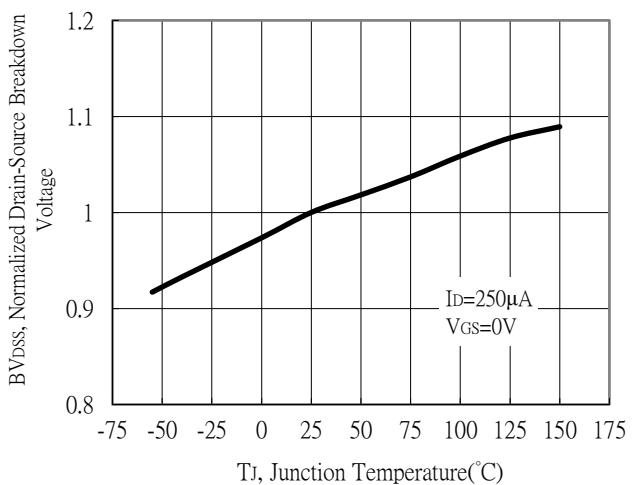
*2. Independent of operating temperature

Typical Characteristics

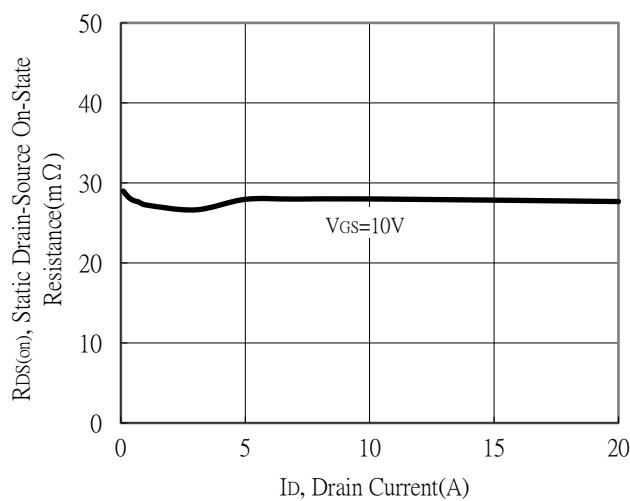
Typical Output Characteristics



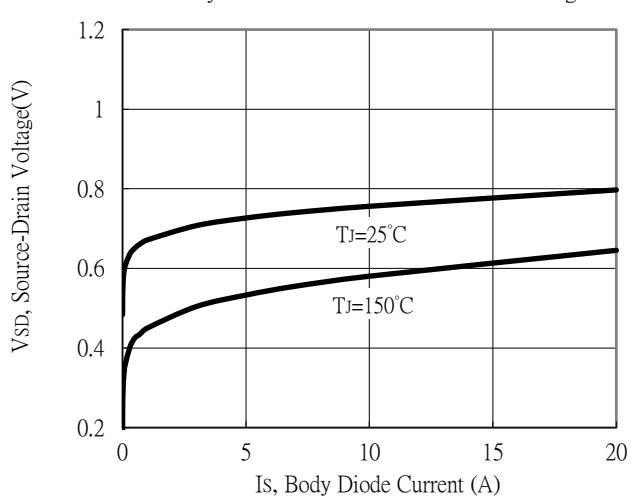
Breakdown Voltage vs Ambient Temperature



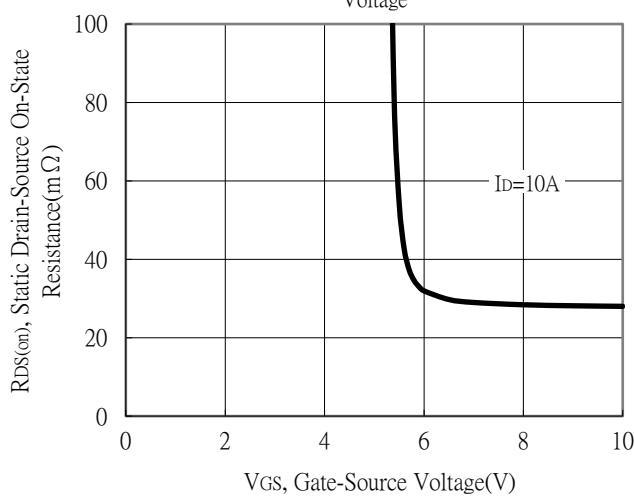
Static Drain-Source On-State resistance vs Drain Current



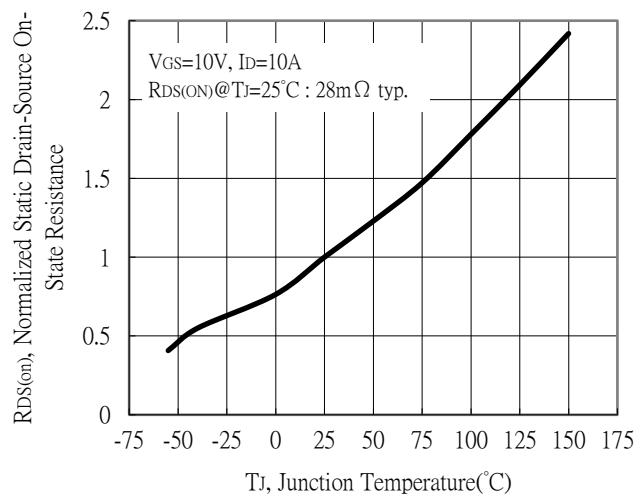
Body Diode Current vs Source-Drain Voltage



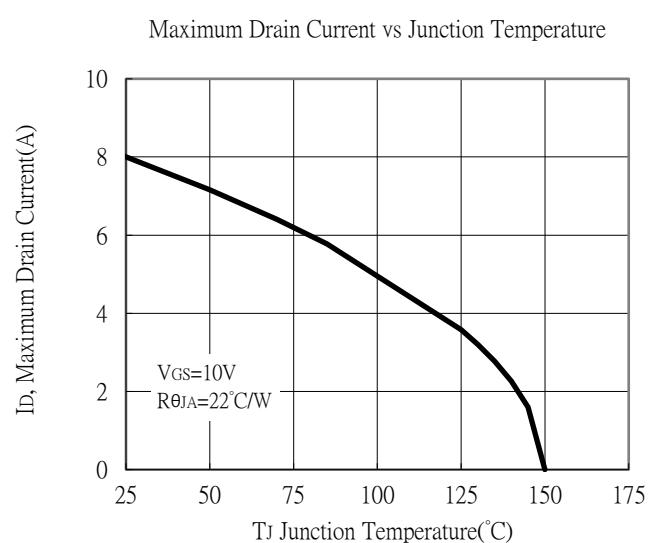
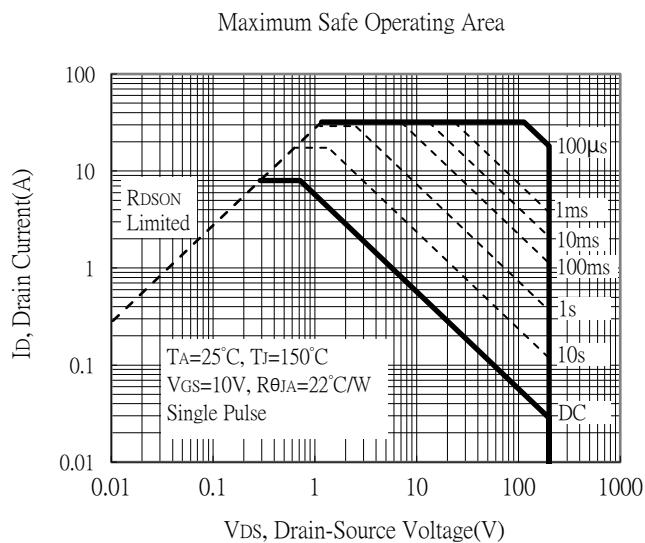
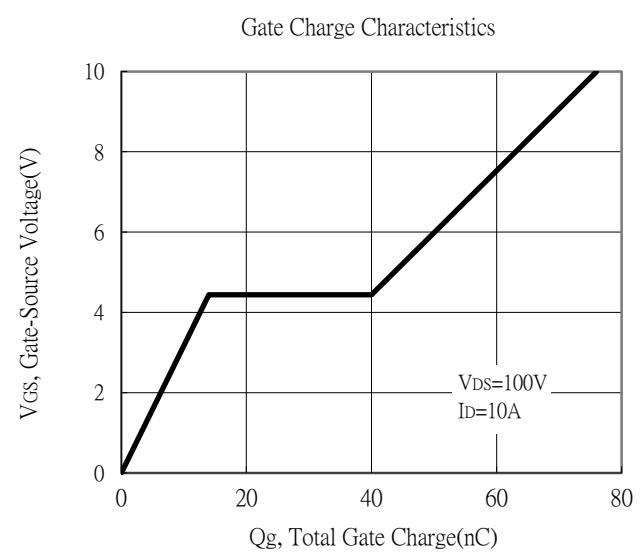
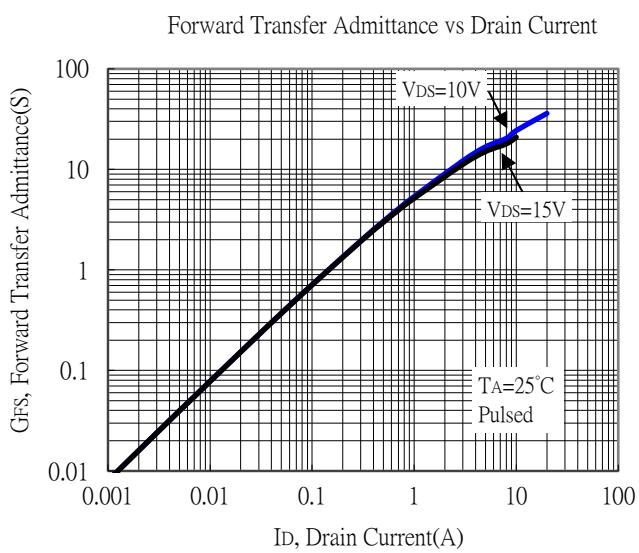
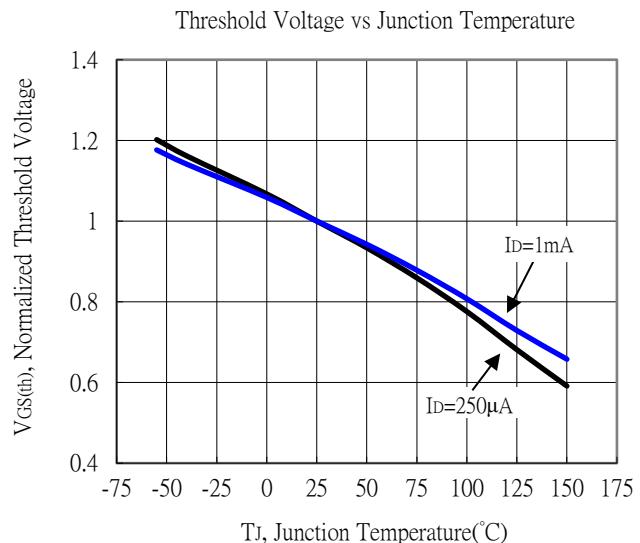
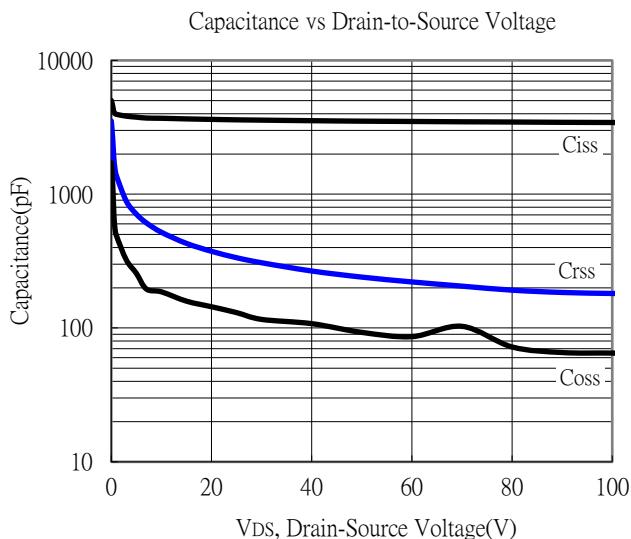
Static Drain-Source On-State Resistance vs Gate-Source Voltage



Drain-Source On-State Resistance vs Junction Temperature

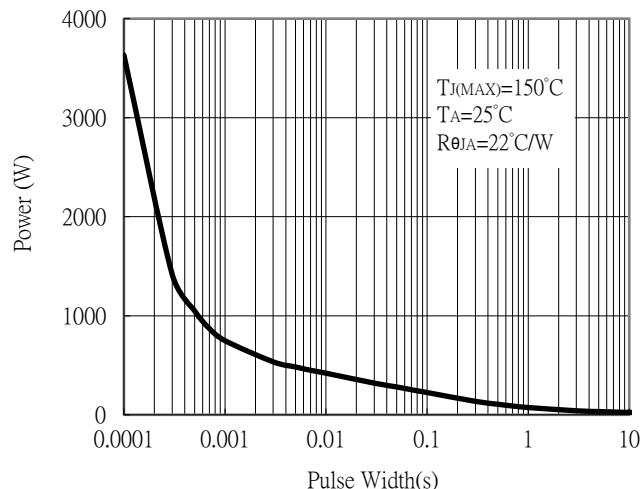


Typical Characteristics (Cont.)

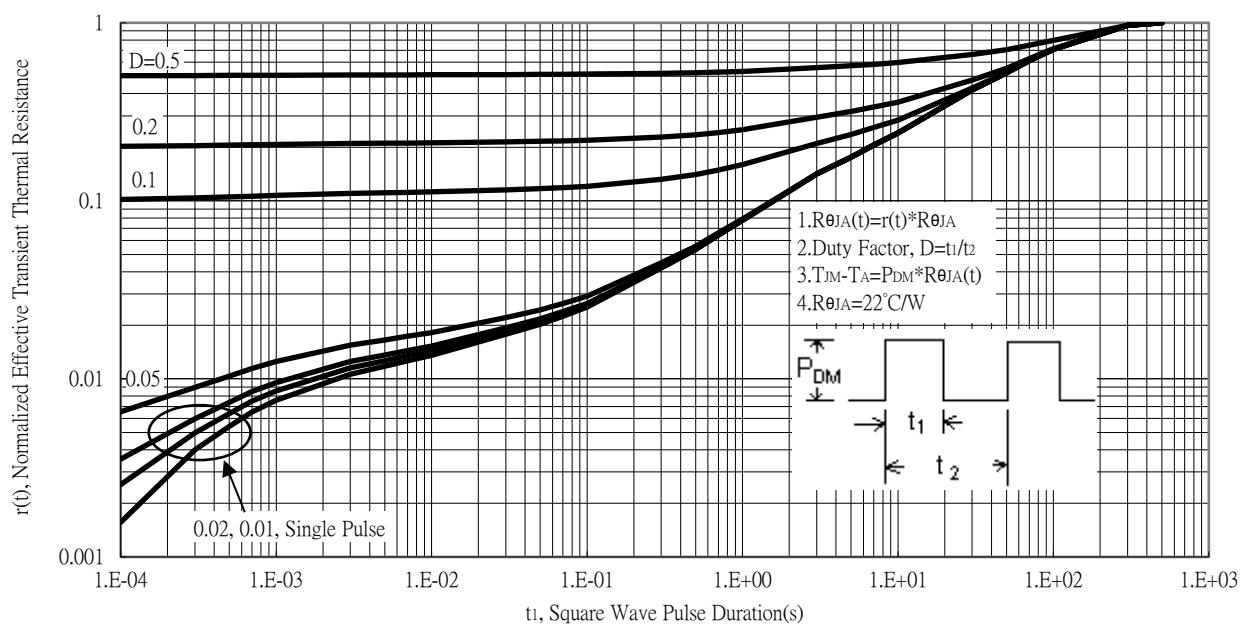


Typical Characteristics (Cont.)

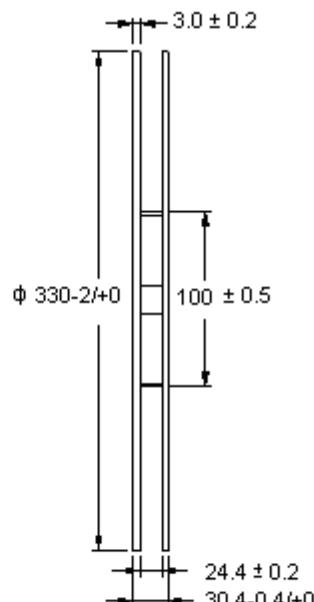
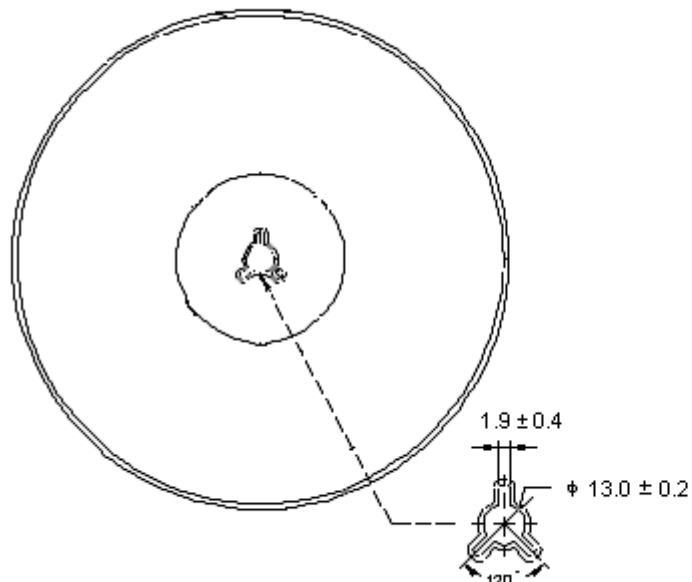
Single Pulse Power Rating, Junction to Ambient



Transient Thermal Response Curves

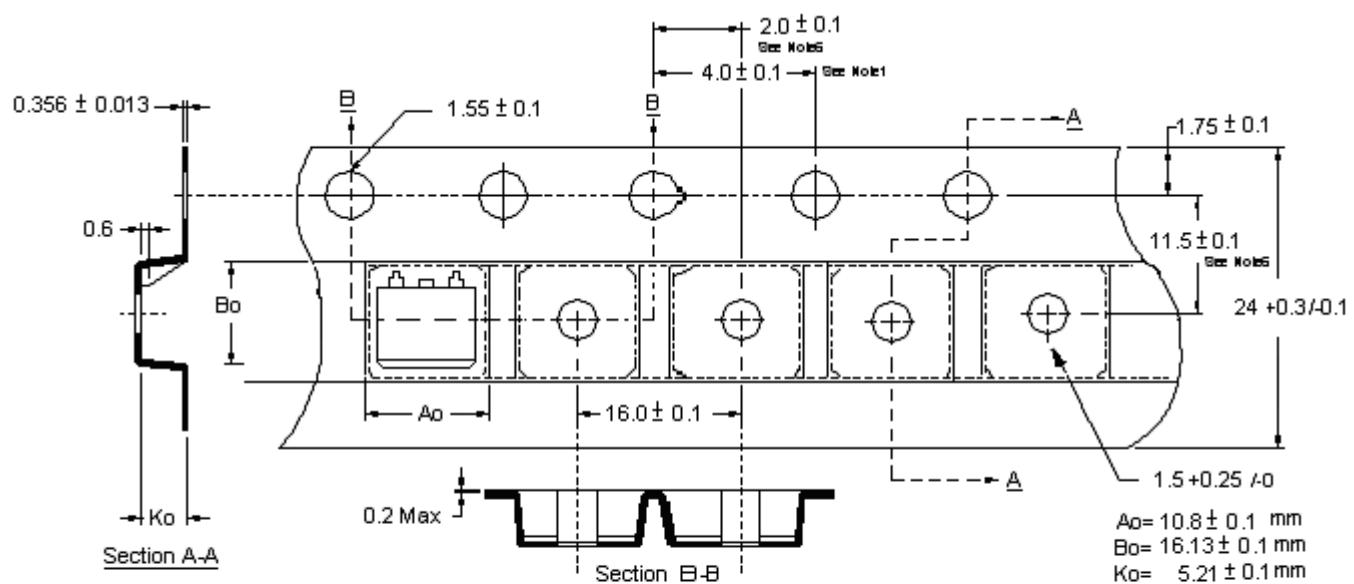


Reel Dimension



Unit: millimeter

Carrier Tape Dimension

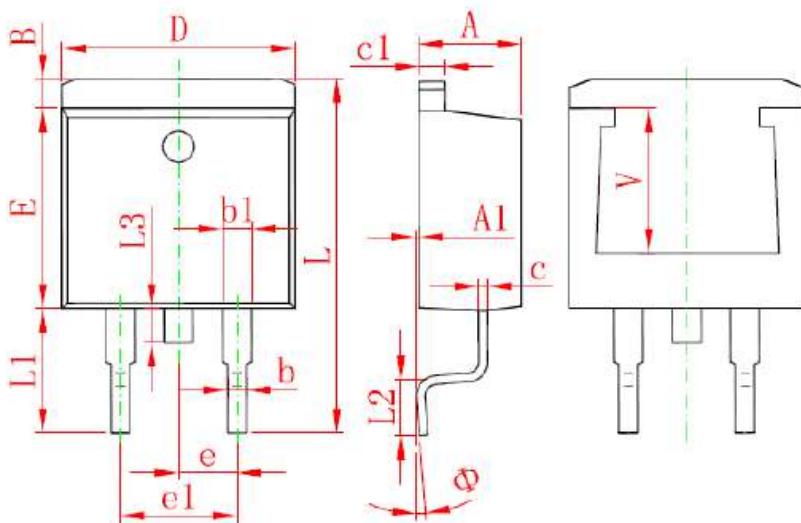


Notes:

1. 10 sprocket hole pitch cumulative tolerance ± 0.2 .
2. Camber not to exceed 1mm in 100mm.
3. Material: Conductive Black Advantek Polystyrene.
4. A_o & B_o measured on a plane 0.3mm above the bottom of the pocket.
5. K_o measured from a plane on the inside bottom of the pocket to the top surface of the carrier.
6. Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.

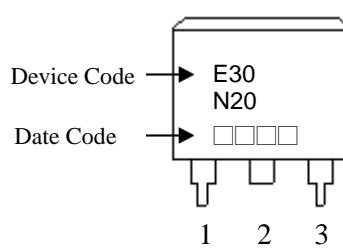
Unit : millimeter

TO-263 Dimension



3-Lead Plastic Surface Mounted Package

Marking :



Style : Pin 1.Gate 2.Drain
 3.Source

Date Code(counting from left to right) :

1st code: year code, the last digit of Christian year
 2nd code : month code, Jan→A, Feb→B, Mar→C,

Apr→D, May→E, Jun→F, Jul→G, Aug→H,
 Sep→J, Oct→K, Nov→L, Dec→M

3rd and 4th codes : production serial number, 01~99

DIM	Millimeters		Inches		DIM	Millimeters		Inches	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	4.470	4.670	0.176	0.184	e	2.540	TYP	0.100	TYP
A1	0.000	0.150	0.000	0.006	e1	4.980	5.180	0.196	0.204
B	1.120	1.420	0.044	0.056	L	14.940	15.500	0.588	0.610
b	0.710	0.910	0.028	0.036	L1	4.950	5.450	0.195	0.215
b1	1.170	1.370	0.046	0.054	L2	2.340	2.740	0.092	0.108
c	0.310	0.530	0.012	0.021	L3	1.300	1.700	0.051	0.067
c1	1.170	1.370	0.046	0.054	Φ	0°	8°	0°	8°
D	10.010	10.310	0.394	0.406	V	5.600	REF	0.220	REF
E	8.500	8.900	0.335	0.350					